

MOSFETs Silicon N-Channel MOS (DTMOS II)

TK40J60U

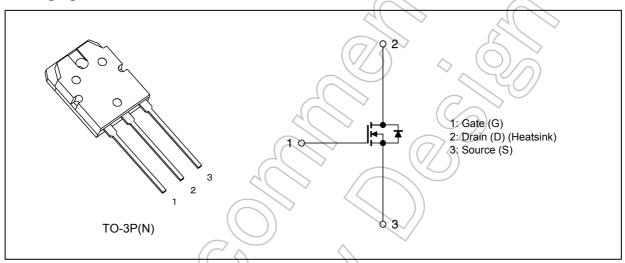
1. Applications

· Switching Voltage Regulators

2. Features

- (1) Low drain-source on-resistance: $R_{DS(ON)} = 0.065 \Omega$ (typ.)
- (2) High forward transfer admittance: $|Y_{fs}| = 30 \text{ S (typ.)}$
- (3) Low leakage current: $I_{DSS} = 100 \mu A \text{ (max) (V}_{DS} = 600 \text{ V)}$
- (4) Enhancement mode: $V_{th} = 3.0 \text{ to } 5.0 \text{ V } (V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA})$

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) (Ta = 25°C unless otherwise specified)

| Characteristics | 77/^ | Symbol | Rating | Unit |
|---|----------|------------------|------------|------|
| Drain-source voltage | ()) | V _{DSS} | 600 | V |
| Gate-source voltage | | V _{GSS} | ±30 | |
| Drain current (DC) | (Note 1) | I _D | 40 | Α |
| Drain current (pulsed) | (Note 1) | I _{DP} | 80 | |
| Power dissipation (T _c = 25°C) | | P _D | 320 | W |
| Single-pulse avalanche energy | (Note 2) | E _{AS} | 540 | mJ |
| Avalanche current | | I _{AR} | 20 | Α |
| Repetitive avalanche energy | (Note 3) | E _{AR} | 32 | mJ |
| Channel temperature | | T _{ch} | 150 | ů |
| Storage temperature | | T _{stg} | -55 to 150 | |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Start of commercial production



5. Thermal Characteristics

| Characteristics | Symbol | Max | Unit |
|---------------------------------------|-----------------------|------|------|
| Channel-to-case thermal resistance | R _{th(ch-c)} | 0.39 | °C/W |
| Channel-to-ambient thermal resistance | R _{th(ch-a)} | 50 | |

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V_{DD} = 90 V, T_{ch} = 25°C (initial), L = 2.36 mH, R_G = 25 Ω , I_{AR} = 20 A

Note 3: Repetitive rating; pulse width limited by maximum channel temperature

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.



6. Electrical Characteristics

6.1. Static Characteristics (T_a = 25°C unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------|----------------------|---|-----|-------|------|------|
| Gate leakage current | I _{GSS} | $V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$ | _ | _ | ±1 | μΑ |
| Drain cut-off current | I _{DSS} | V _{DS} = 600 V, V _{GS} = 0 V | | _ | 100 | |
| Drain-source breakdown voltage | V _{(BR)DSS} | I_D = 10 mA, V_{GS} = 0 V | 600 | | | V |
| Gate threshold voltage | V_{th} | $V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$ | 3.0 |) ~ | 5.0 | |
| Drain-source on-resistance | R _{DS(ON)} | V _{GS} = 10 V, I _D = 20 A | | 0.065 | 0.08 | Ω |
| Forward transfer admittance | Y _{fs} | V _{DS} = 10 V, I _D = 20 A | 7,5 | 30 | | S |

6.2. Dynamic Characteristics (T_a = 25°C unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------|------------------|--|-------|------|---------------|------|
| Input capacitance | C _{iss} | V _{DS} = 10 V, V _{GS} = 0 V, f = 0.1 MHz | _ | 3400 | \rightarrow | pF |
| Reverse transfer capacitance | C _{rss} | | | 180 | | |
| Output capacitance | Coss | ((//5) | _((| 7800 | _ | |
| Switching time (rise time) | t _r | See Figure 6.2.1. | 7 | (60) |) — | ns |
| Switching time (turn-on time) | t _{on} | | | 120 | _ | |
| Switching time (fall time) | t _f | | | 13 | _ | |
| Switching time (turn-off time) | t _{off} | | //-// | 160 | _ | |

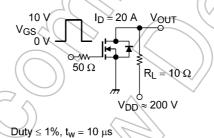


Fig. 6.2.1 Switching Time Test Circuit

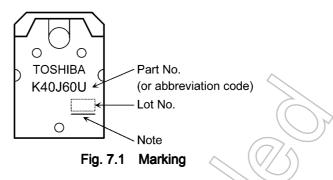
6.3. Gate Charge Characteristics (T_a = 25°C unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|-----------------|---|-----|------|-----|------|
| Total gate charge (gate-source plus gate-drain) | Qg | $V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 40 \text{ A}$ | _ | 55 | _ | nC |
| Gate-source charge | Q _{gs} | | _ | 37 | _ | |
| Gate-drain charge | Q_{gd} | | _ | 18 | _ | |

6.4. Source-Drain Characteristics (T_a = 25°C unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|------------------|---|-----|------|------|------|
| Reverse drain current (DC) (Note 1) | I _{DR} | _ | | | 40 | Α |
| Reverse drain current (pulsed) (Note 1) | I _{DRP} | _ | | | 80 | |
| Diode forward voltage | V _{DSF} | I _{DR} = 40 A, V _{GS} = 0 V | _ | _ | -1.7 | V |
| Reverse recovery time | t _{rr} | I _{DR} = 40 A, V _{GS} = 0 V | _ | 520 | _ | ns |
| Reverse recovery charge | Q _{rr} | -dI _{DR} /dt = 100 A/μs | _ | 13 | _ | μС |

7. Marking (Note)



Note: A line under a Lot No. identifies the indication of product Labels.

Not underlined: [[Pb]]/INCLUDES > MCV

Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

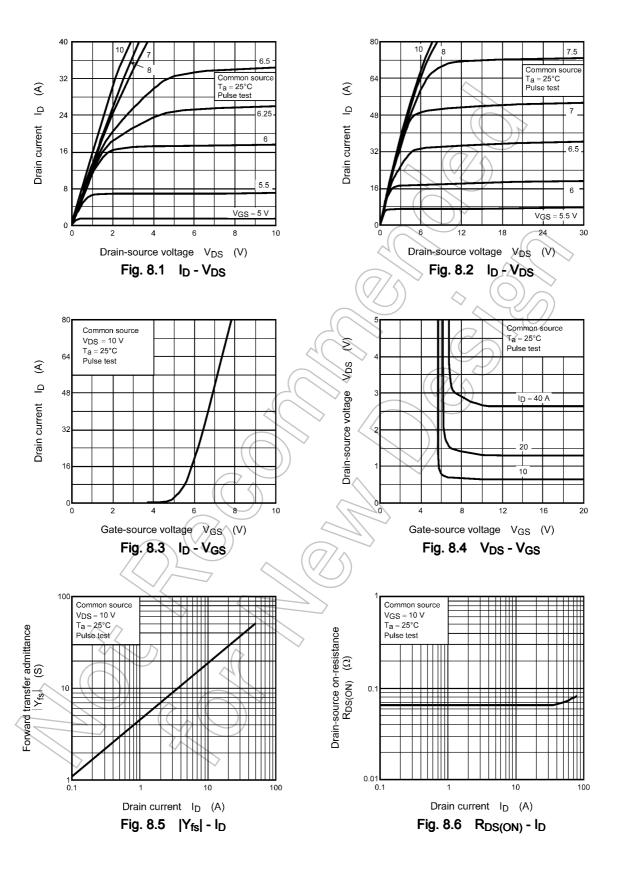
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.



Rev.4.0

8. Characteristics Curves (Note)



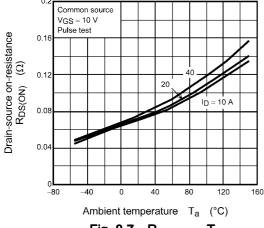


Fig. 8.7 RDS(ON) - Ta

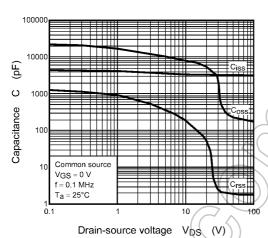


Fig. 8.9 C - V_{DS}

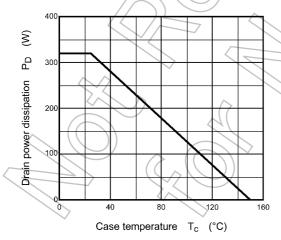


Fig. 8.11 P_D - T_c (Guaranteed Maximum)

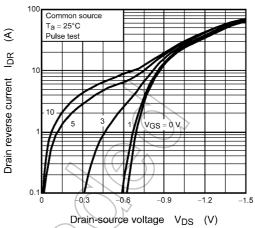


Fig. 8.8 IDR - VDS

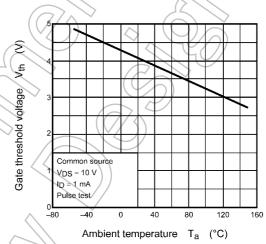


Fig. 8.10 V_{th} - T_a

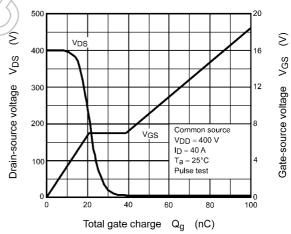


Fig. 8.12 Dynamic Input/Output Characteristics

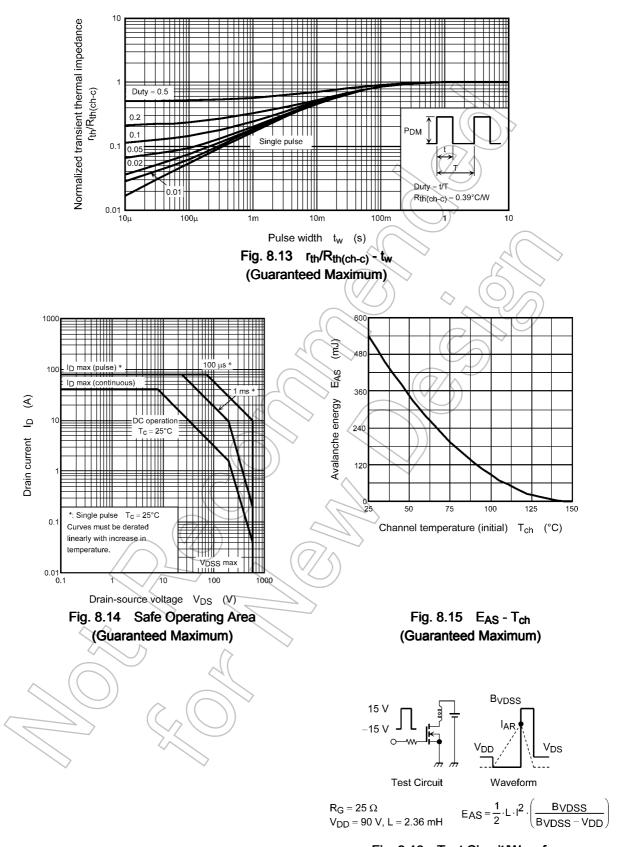


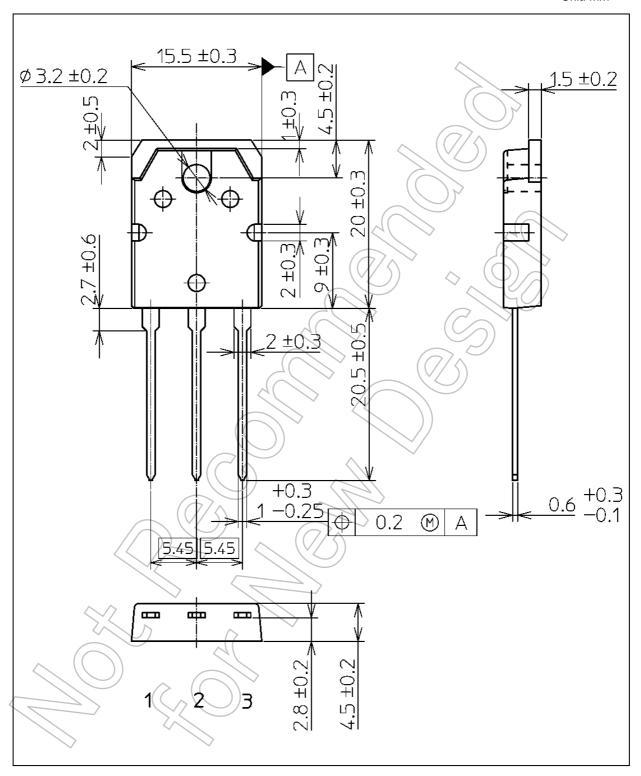
Fig. 8.16 Test Circuit/Waveform

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



Package Dimensions

Unit: mm



Weight: 4.6 g (typ.)

| | Package Name(s) |
|--------------------|-----------------|
| JEITA: SC-65 | |
| TOSHIBA: 2-16C1S | |
| Nickname: TO-3P(N) | |



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